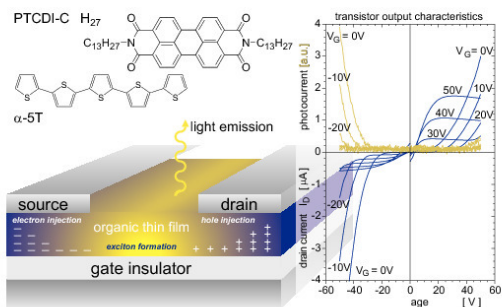





Constance Rost-Bietsch (Autor)
Ambipolar and Light-Emitting Organic Field-Effect Transistors

Constance Rost-Bietsch

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Organic Field-Effect Transistors**



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